

	<p>SI3457CDV-T1-E3</p>
	<p>Manufacturer Part Number: SI3457CDV-T1-E3</p> <p>Manufacturer/Brand: Electro-Films (EFI) / Vishay</p> <p>Part of Description: MOSFET P-CH 30V 5.1A 6-TSOP</p> <p>Datasheets:  SI3457CDV-T1-E3.pdf</p> <p>RoHS Status:  Lead free / RoHS Compliant</p> <p>Stock Condition: New original, 39770 pcs Stock Available.</p> <p>Ship From: Hong Kong</p> <p>Shipment Way: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Specifications

Part Number	SI3457CDV-T1-E3
Manufacturer	Electro-Films (EFI) / Vishay
Description	MOSFET P-CH 30V 5.1A 6-TSOP
Category	Discrete Semiconductor Products > Transistors - FETs,
Part Status	39770 pcs Stock
Detailed Description	P-Channel 30V 5.1A (Tc) 3W (Tc) Surface Mount 6-
Series	TrenchFET®
Technology	MOSFET (Metal Oxide)
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Package / Case	SOT-23-6 Thin, TSOT-23-6
Supplier Device Package	6-TSOP
Power Dissipation (Max)	3W (Tc)
FET Type	P-Channel
FET Feature	-
Drain to Source Voltage (Vdss)	30V
Current - Continuous Drain (Id) @ 25°C	5.1A (Tc)
Rds On (Max) @ Id, Vgs	74 mOhm @ 4.1A, 10V
Vgs(th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	15nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	450pF @ 15V
Drive Voltage (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Packaging	Original-Reel®
Lead Free Status / RoHS Status	Lead free / RoHS Compliant
Moisture Sensitivity Level (MSL)	1 (Unlimited)
Other Names	SI3457CDV-T1-E3DKR

SI3457CDV-T1-E3 is New Original in Stock, Search SI3457CDV-T1-E3 Datasheets, PDF, Inventory at Y-IC.com Online, Order SI3457CDV-T1-E3 Electro-Films (EFI) / Vishay with warrantied and confidence. RFQ SI3457CDV-T1-E3 : Info@Y-IC.com

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 <p>SI3457BDV-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 30V 3.7A 6-TSOP</p>	 <p>SI3457DV Fairchild/ON Semiconductor MOSFET P-CH 30V 4A SSOT-6</p>	 <p>SI3457CDV-T1-GE3 Vishay / Siliconix MOSFET P-CH 30V 5.1A 6-TSOP</p>	 <p>SI3457BDY-T1 VISHAY VISHAY sot163</p>

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- D SI3456CDV-T1-GE3
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- ⚙ SI3456DDV-T1-GE3
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- ➡ SI3456DV-NL
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- ➡ SI3459DV-T1-GE3
- ➡ SI3460-E02-GMR
- ➡ SI3460-E03-GMR

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